NSN 5961-01-361-5553

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-361-5553 **Inclosure Material:** Metal **Overall Length:** 1.563 inches **Overall Height:** 0.672 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204ae **Electrode Internally-electrically Connected To Case: Mounting Method:** Unthreaded hole **Features Provided:** Electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 drain to source voltage and 40.0 gate to source voltage **Power Rating Per Characteristic:** 250.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No